IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Jerome M. Eldridge et al.

Applicant: Serial No.: 10/081,818

Examiner: Tu-Tu V. Ho Group Art Unit: 2818

Filed:

Docket: 1303.045US1

Title:

February 20, 2002 ATOMIC LAYER DEPOSITION OF METAL OXIDE AND/OR LOW

ASYMMETRICAL TUNNEL BARRIER INTERPLOY INSULATORS

COMMUNICATION CONCERNING RELATED APPLICATION(S)

MS Issue Fee

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

Serial/Patent No. Filing Date/Issue Date 11/565,826

December 1, 2006

Attorney Docket 1303.141US2

Title

HAFNIUM TITANIUM OXIDE FILMS

12/207.141

September 9, 2008

1303.028US3

SRAM CELLS WITH REPRESSED FLOATING GATE MEMORY, LOW TUNNEL BARRIER INTERPOLY

INSULATORS

Continuations and divisionals may be later filed on the cases listed above, or cited to the Examiner in any previous Communication Concerning Related Applications. Applicants request that the Examiner review all continuations and divisionals of the above-listed or previously-cited natent applications before allowing the claims of the present patent application.

Respectfully submitted.

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CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being filed using the USPTO's electronic filing system EFS-Web, and is addressed to: MS Issue Fee, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this _____ day of November, 2008.

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